



Europäisches Patentamt
European Patent Office
Office européen des brevets



⑪ Publication number: **0 528 676 A1**

4/4

⑫

EUROPEAN PATENT APPLICATION

⑬ Application number: **92307519.6**

⑮ Int. Cl.⁵: **G01T 1/20, G01T 1/29,**

⑭ Date of filing: **18.08.92**

H01L 31/0203, H01L 31/0216

⑯ Priority: **21.08.91 US 747827**

⑰ Inventor: Kingsley, Jack Dean

⑯ Date of publication of application:
24.02.93 Bulletin 93/08

2121 Orchard Park Drive

Schenectady, New York 12309 (US)

⑯ Designated Contracting States:
DE FR NL

Inventor: Lubowski, Stanley Joseph

132 Spring Road

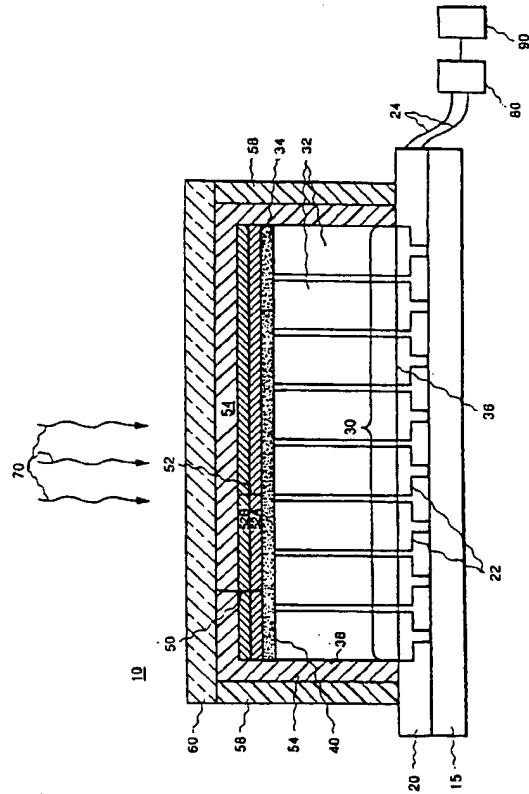
Scotia, New York 12302 (US)

⑰ Applicant: **GENERAL ELECTRIC COMPANY**
1 River Road
Schenectady, NY 12345 (US)

⑰ Representative: Lupton, Frederick et al
LONDON PATENT OPERATION, G.E.
TECHNICAL SERVICES Co. INC., Essex
House, 12/13 Essex Street
London WC2R 3AA (GB)

④ A solid state radiation imager having a reflective and protective coating.

⑤ A radiation imager having a scintillator (30) mated to a photodetector array (20) has a moisture barrier (50) disposed over at least the portion of the scintillator exposed to the incident radiation (70). The moisture barrier (50), which is substantially impervious to moisture, is both radiation transmissive and optically reflective. A pellicle layer (40) may be disposed between the top surface of the scintillator array (20) and the moisture barrier (50) to provide a stable surface to which the moisture barrier can adhere. The moisture barrier normally comprises an optically reflective layer (52) and a moisture sealant layer (54). The optically reflective layer is comprised of a reflective metal or dielectric layers (52B,52A) having different refractive indices and the moisture sealant layer (54) is comprised of a silicone potting compound. A hardened protective window (60) may be situated over the top surface of the moisture barrier.



FHP 99-15 AEPIC
03.10.15
SEARCH REPORT

EP 0 528 676 A1

Jouve, 18, rue Saint-Denis, 75001 PARIS

Field of the Invention

This invention relates generally to radiation imaging systems and more particularly to scintillators coupled to photodetectors for use in such systems.

Background of the Invention

Reference is made to our copending Application Serial No. (RD-20, 267), no. , and entitled "Planar X-Ray Imager Having A Moisture-Resistant Sealing Structure".

Radiation imaging systems are widely used for medical and industrial purposes. Imaging systems have been developed which use detected radiation to produce a signal which can be used to operate a visual display device or which can be used for other analyses of the pattern of detected electromagnetic radiation such as x-ray or gamma ray radiation. In such systems the radiation is typically absorbed in a scintillator material, resulting in the generation of photons of light. Light photons emanating from the scintillator are detected by the photodetectors to generate an electrical output signal that can be processed to drive the display or analysis system.

The scintillator material may be in the form of a solid block or may be divided into separate elements, such as by dicing or cutting, or by depositing the scintillator material in such a manner that individual columns or peaks are formed. It is important to protect the scintillator material from moisture absorption. For example, cesium iodide, a common scintillator material, is a hygroscopic material, that is, it exhibits a tendency to absorb moisture from the atmosphere around it; in so doing it becomes hydrolized with a consequent degradation in its luminescent properties. In a radiation detector it is also beneficial to maximize the efficiency with which the luminescence from the scintillator is collected by the photodiodes by ensuring that the majority of photons generated in the absorption event are directed to the photodetectors.

Covering the scintillator with a thin coating is difficult due to the irregularly shaped ends or surfaces of the scintillator material, such as typically result from the common evaporative deposition processes used in formation of scintillators. Such irregular surfaces require that any coating be at least initially pliable so as to conform to the surface of the scintillator, and require that a stable and adherent surface be prepared to allow the deposition of an uniform layer of optical reflective material, such as a metal. Typical prior art imagers, such as the device of Derenzo disclosed in U.S. Patent No. 4,672,207, do not suggest any protective or reflective coating for the surfaces of the scintillator.

Summary of the Invention

It is accordingly an object of this invention to provide a protective coating for the scintillator elements of an imager, which coating will serve as a barrier to inhibit absorption of moisture by the scintillator from the atmosphere surrounding the scintillator.

In one aspect, the invention provides a radiation imaging device comprising a scintillator having a first and a second surface, said first and second surfaces being opposite one another, the radiation incident on said device entering said scintillator through said first surface; an array of photodetectors, said photodetectors being optically coupled to, said second surface of said scintillator to receive light therefrom; and a moisture barrier, said moisture barrier being substantially impervious to moisture and being optically reflective and radiation transmissive, said moisture barrier further being disposed at least over said first surface of said scintillator, forming a moisture resistant seal thereover.

In another aspect, the invention provides a radiation imaging device comprising an array of scintillator elements, said scintillator elements each having a first and a second end, said first and second ends being opposite one another, the radiation incident on said device entering said elements through said first end; an array of solid state photodetectors, said photodetectors being optically coupled to said second ends of said scintillator elements to receive light therefrom; a moisture barrier, said moisture barrier substantially impervious to moisture and being optically reflective and x-ray and gamma radiation transmissive, said moisture barrier further being disposed at least over said first ends of said scintillator elements, forming a moisture resistant seal thereover; a processing circuit coupled to receive signals generated by said photodetector array; and display and analysis equipment coupled to, and responsive to, said processing circuit.

In accordance with the present invention, a radiation imaging device comprises a scintillator, an array of photodetectors which is optically coupled to the scintillator, and a moisture barrier disposed over the surface of the scintillator through which the incident radiation enters the device. The moisture barrier is substantially impervious to moisture, radiation transmissive, and optically reflective.

In a typical arrangement, the moisture barrier is comprised of at least two layers, a moisture sealant layer and an optically reflective layer. The moisture sealant layer comprises a silicone potting compound, and the optically reflective layer comprises relatively thin layers of a metal or combination of metals such as silver, gold, or aluminum. A pellicle layer is disposed between the moisture barrier and the scintillator to provide a thin coating that acts as a stable surface to which the moisture barrier can adhere. The

scintillator can be encapsulated by the moisture sealant layer extending around all surfaces of the array which are not coupled to the photodetector array. The moisture barrier can be augmented and protected from abrasion or puncture by the placement of a hardened, radiation transmissive window across the portion of the moisture barrier that covers the surface of the scintillator exposed to the incident radiation.

The invention thus provides a sealed environment which protects the scintillator from moisture absorption and that reflects light photons back into, the scintillator elements in the direction of the photodetector array.

Brief Description of the Drawing

The features of the invention believed to be novel are set forth with particularity in the appended claims. The invention itself, however, both as to organization and method of operation, together with further objects and advantages thereof, may best be understood by reference to the following description in conjunction with the accompanying drawing in which:

The single Figure is a schematic cross sectional diagram of a radiation imaging device in accordance with this invention.

Detailed Description of the Preferred Embodiment

In the single Figure, a radiation imaging device 10 comprises a photodetector array 20 disposed on a substrate 15, a scintillator 30 disposed over the photodetector array, and a moisture barrier 50 having an optically reflective layer 52 and a moisture sealant layer 54 disposed over the scintillator. The photodetector array is coupled to a processing circuit 80, which processes the electrical signals for use in display and analysis equipment 90.

Photodetector array 20 is comprised of a plurality of photodetectors 22 arranged and electrically connected in a pattern, typically rows and columns. The photodetectors are disposed on substrate 15 to form an array that can be of any size and shape appropriate for the use of imaging device 10, such as for medical analyses of particular portions of the body. The photodetectors are advantageously amorphous silicon photodiodes, and alternatively may comprise other known solid state photodetector devices. Cables 24 carry the electrical signals generated in the photodetectors to processing circuit 80.

Scintillator 30 is positioned adjacent to, and optically coupled to, photodetector array 20. As used herein, "optically coupled to photodetector array 20" refers to arranging the two arrays so that light photons from the scintillator readily pass into photodetectors; the optical coupling may include a separate layer (not shown) of a material which aids in the efficient

transfer of the photons from the scintillator to the photodetectors. Scintillator 30 advantageously may be divided into a plurality of separate scintillator elements 32, as shown, or may alternatively comprise a single, substantially homogeneous block of scintillator material (not shown). Scintillator elements 32 may be diced, or cut, from a larger block of scintillator material or may be separately grown or deposited in columnar structures using a known method such as vapor deposition or sputtering. After the deposition process, the surface of the scintillator may be irregular or have protrusions. Scintillator 30 may be grown, or deposited, directly onto photodetector array 20 or may be separately formed and then aligned with, and mated to, photodetector array 20. Scintillator elements 32 are arranged in an array that substantially corresponds to the arrangement of photodetector array 20. The scintillator has a first end or surface 34 through which incident x- or gamma radiation 70 enters, and a second end or surface 36, which is opposite to the first end or surface, through which the light photons pass to the adjoining photodetector array 20. The material that is used to form scintillator 30 is typically cesium iodide, but can alternatively comprise other known scintillating materials.

In accordance with the present invention a moisture barrier 50 is disposed over at least the top of scintillator array 30, extending over first surface 34 of scintillator 30 to seal the scintillator from moisture that may be present in the atmosphere around imaging device 10. Particularly when first surface 34 of the scintillator is rough or has an uneven shape, such as when scintillator elements 32 have been deposited in columnar structures, pellicle layer 40 is advantageously disposed over first surface 34 of the scintillator. Pellicle layer 40 adheres well to the uneven surface of the scintillator and provides a stable, i.e. firm and reasonably smooth, surface to which moisture barrier 50 can adhere. The pellicle layer is typically very thin, having a thickness between about 200 to 600 Angstroms, and comprises organic materials such as nitrocellulose, poly(para-xylene), or organopolysiloxane-polycarbonate, or alternatively comprises inorganic material such as kryolite. Pellicle layer 40 can be made in any conventional manner, such as by preparation of the thin layer on a water bath and then setting the layer into place.

Moisture barrier 50 is substantially impervious to moisture, is optically reflective, and is radiation transmissive. As used in the context of this invention, as applied to moisture barrier 50, "impervious to moisture" means that the barrier forms a seal which prevents moisture in liquid or vapor form from passing across the barrier; "optically reflective" refers to the property of moisture barrier 50 that causes light photons emanating from the scintillator to be reflected back into the scintillator, thus minimizing the amount of light which escapes the scintillator and is not de-

tected by a photodetector, and "radiation transmissive" refers to radiation of the type to be detected by the device and signifies that the barrier typically does not strongly interact with the material forming the barrier, thus allowing the maximum amount of the incident radiation to enter the scintillator without absorption or scattering.

As illustrated in the Figure, moisture barrier 50 comprises an optically reflective layer 52 and a moisture sealant layer 54. Optically reflective layer 52 is advantageously made of a highly reflective metal such as silver, gold, aluminum or the like, or may be formed as a multi-layer dielectric mirror. The thickness of a metallic reflector would advantageously be in the range of about 100 to about 2000 angstroms. Because of the chemical reactivity of silver, layer 52 advantageously is composed of two or more sublayers 52A, 52B, wherein sublayer 52A preferably is silver and sublayer 52B advantageously is either of gold or a similarly less reactive metal. If reflective layer 52 is a multi-layer dielectric mirror, the adjoining sublayers would have materials which have significantly different refractive indices; for example, the sublayers may advantageously be formed of silicon dioxide, which has a refractive index of about 1.45, and titanium oxide, which has a refractive index of about 2.6. Alternatively, tantalum oxide can be substituted for titania; other materials having suitable refractive indices and capable of being deposited in thin films from the vapor phase can alternatively be used. The design of dielectric mirrors is well known to those skilled in the art, with the thicknesses and number of layers dependent on the range of wavelengths to be reflected. Such mirrors may have about 10 to about 20 layers.

Moisture sealant layer 54 is disposed over scintillator 30, and at least extends over optically reflective layer 52. Moisture sealant layer 54 advantageously extends around the outer edges or sidewalls 38 of scintillator 30 along the length of the scintillator from first surface 34 to second surface 36. Enclosure walls 58 disposed on photodetector array 20 run substantially parallel to outer edges 38 of the scintillator. The enclosure walls serve to retain moisture sealant layer 54, which can, at least when initially applied, be in a liquid form and cure to a harder state after application, against scintillator sidewalls 38. By way of example and not limitation, enclosure walls 58 may comprise a bead or dam of epoxy laid down around the outer edges of the scintillator. The scintillator can thus be encapsulated to minimize locations where the scintillator material might be exposed to moisture present in the ambient environment or atmosphere around device 10. The interface formed by the optical coupling of scintillator 30 to photodetector array 20 typically results in the scintillator array being sealed from moisture along that interface.

Moisture sealant layer 54 is preferably a silicone

potting compound such as GE Silicone Gel RTV 6157, Dow Corning Sylgard® or a similar material that is substantially impervious to moisture and not reactive to the radiation flux to which it is exposed in this structure. Sealant layer 54 typically has a thickness between about 1/4 mm and 1 mm.

A radiation transmissive window 60 is disposed over the top surface of moisture barrier 50 to provide a hardened protective surface over moisture sealant layer 54. As illustrated in the Figure, window 60 contacts enclosure walls 58 and thus can provide additional structural strength to device 10; alternatively, window 60 may be disposed only over the top surface of moisture sealant layer 54. Window 60 may be positioned on the device after moisture sealant layer 54 has been applied to optically reflective layer 52, or alternatively, moisture sealant layer 54 may be applied to window 60 first, and the window can then be positioned on the device 10 before moisture sealant layer 54 has cured. Radiation transmissive materials that are advantageously used in the fabrication of window 60 include quartz glass, aluminum, aluminum oxide ceramic, beryllium and the like.

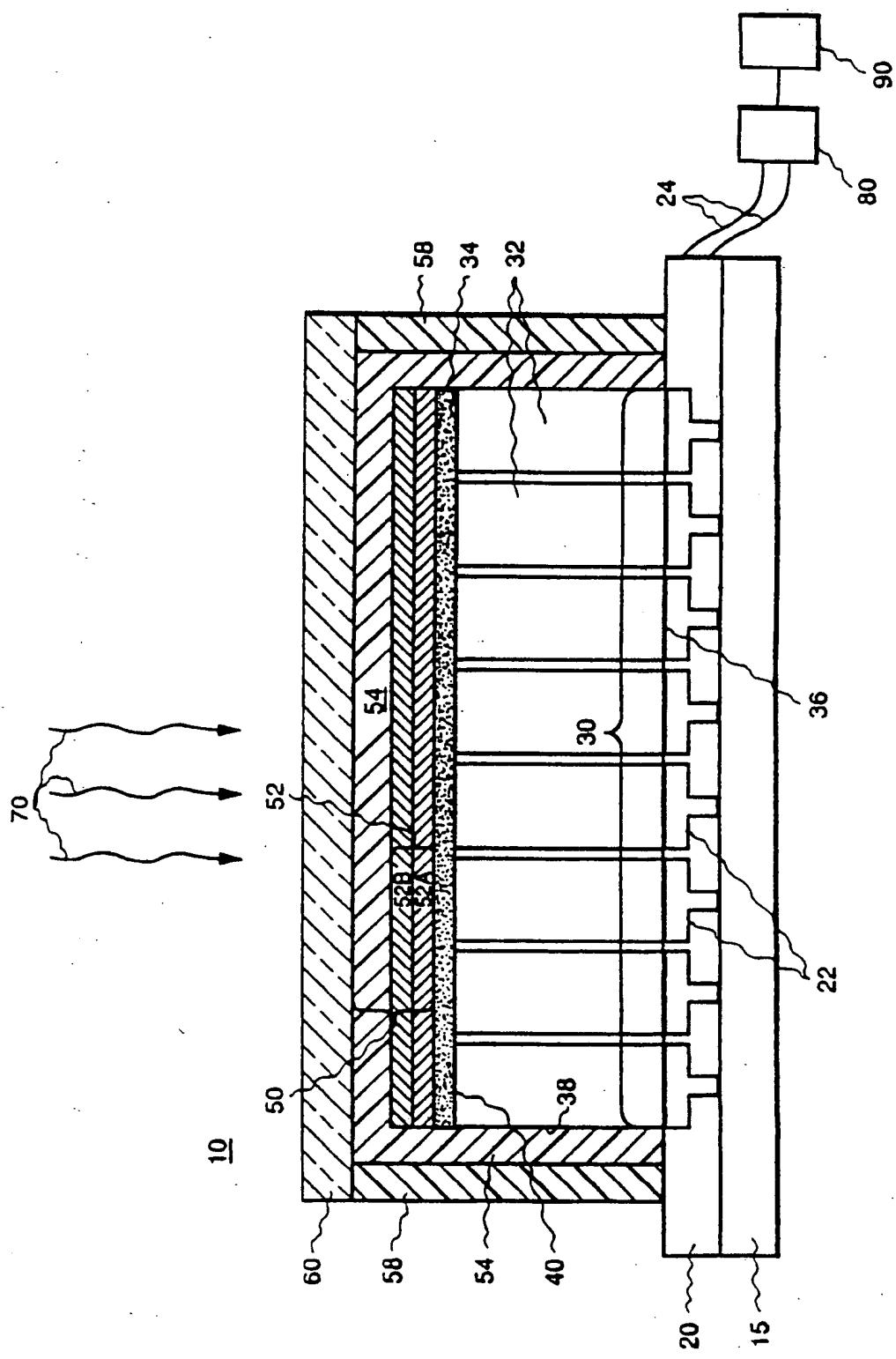
In operation, device 10 is positioned to be in the path of incident radiation 70 that is of interest. The radiation, which may be x-rays, gamma rays, or other radiation detectable via the use of scintillators and photodetectors, passes through window 60, moisture barrier 50, pellicle layer 40 and into scintillator 30, where it interacts with the scintillator material and is absorbed. In the interaction, light photons are given off, more or less in random directions. Light photons that emanate toward the first surface 34 of the scintillator 30, or that are reflected in that direction after striking the walls of the scintillator, pass through the pellicle layer but are reflected back into the scintillator by optically reflective layer 52. Light photons are thus directed to second surface 36 of the scintillator, where they exit the scintillator and enter the photodetector mounted adjacent to the scintillator. The photodetectors generate an electrical signal which corresponds to the energy level of the incident radiation and which is processed by processing circuit 80. Circuit 80 is coupled to imaging and analysis equipment 90, which is responsive to the electrical signals generated in processing circuit 80.

While only certain features of the invention have been illustrated and described herein, many modifications and changes will occur to those skilled in the art. It is, therefore, to be understood that the appended claims are intended to cover all such modifications and changes as fall within the true spirit of the invention.

Claims

1. A radiation imaging device comprising:

- a scintillator having a first and a second surface, said first and second surfaces being opposite one another, the radiation incident on said device entering said scintillator through said first surface;
- an array of photodetectors, said photodetectors being optically coupled to, said second surface of said scintillator to receive light therefrom; and
- a moisture barrier, said moisture barrier being substantially impervious to moisture and being optically reflective and radiation transmissive, said moisture barrier further being disposed at least over said first surface of said scintillator, forming a moisture resistant seal thereover.
2. A radiation imaging device comprising:
- an array of scintillator elements, said scintillator elements each having a first and a second end, said first and second ends being opposite one another, the radiation incident on said device entering said elements through said first end;
- an array of solid state photodetectors, said photodetectors being optically coupled to said second ends of said scintillator elements to receive light therefrom;
- a moisture barrier, said moisture barrier substantially impervious to moisture and being optically reflective and x-ray and gamma radiation transmissive, said moisture barrier further being disposed at least over said first ends of said scintillator elements, forming a moisture resistant seal thereover,
- a processing circuit coupled to receive signals generated by said photodetector array; and
- display and analysis equipment coupled to, and responsive to, said processing circuit.
3. The device of claim 1 or 2 further comprising a pellicle layer disposed between said moisture barrier and said first surface of said scintillator, said pellicle layer forming a stable surface to which said moisture barrier adheres.
4. The device of claim 1 or 2 further comprising a radiation transmissive window disposed over at least the portion of said moisture barrier overlying said first surface of said scintillator, said window providing a hardened protective surface over said moisture barrier.
5. The device of any preceding claim wherein said moisture barrier comprises an optically reflective layer and a moisture sealant layer.
6. The device of claim 5 wherein said moisture sealant layer extends around the outer edges of said scintillator.
7. The device of claim 5 or 6 wherein said optically reflective layer further comprises a plurality of sublayers.
- 5 8. The device of any of Claims 5 to 7 wherein said optically reflective layer comprises arterial selected from the group consisting of silver, gold, and aluminum.
- 10 9. The device of claim 7 wherein said sublayers comprise dielectric material, each sublayer of dielectric material having an optical index different than the optical index of adjoining sublayers.
- 15 10. The device of any of Claims 5 to 9 wherein the thickness of said optically reflective layer is between about 100 and 2000 Angstroms.
- 20 11. The device of any of Claims 5 to 10 wherein said moisture sealant layer comprises a silicon potting compound.
- 25 12. The device of any preceding claim wherein said photodetectors comprises amorphous silicon photodiodes.
- 30 13. The device of claim 3 wherein said pellicle layer comprises material selected from the group consisting of nitrocellulose, poly(para-xylene), organopolysiloxane-polycarbonate, and kryolite.
- 35 14. The device of any preceding claim where said scintillator comprises cesium iodide.
- 40 15. The device of claim 4 wherein said radiation transmissive window comprises a material selected from the group consisting of quartz glass, aluminum, aluminum oxide ceramic, and beryllium.
- 45
- 50
- 55





European Patent
Office

EUROPEAN SEARCH REPORT

Application Number

DOCUMENTS CONSIDERED TO BE RELEVANT			EP 92307519.6
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. CL5)
X	PATENT ABSTRACTS OF JAPAN, unexamined applications, P field, vol. 11, no. 260, August 22, 1987 THE PATENT OFFICE JAPANESE GOVERNMENT page 38 P 608 * No. 62-63 881 (HORIBA LIMITED) *	1, 2, 5, 6, 14	G 01 T 1/20 G 01 T 1/29 H 01 L 31/0203 H 01 L 31/0216
Y	PATENT ABSTRACTS OF JAPAN, unexamined applications, P field, vol. 13, no. 355, August 09, 1989 THE PATENT OFFICE JAPANESE GOVERNMENT page 104 P 914 * No. 1-114 780 (KANEFUCHI), *	1, 2, 4, 5, 6, 8, 12, 14, 15	
Y	<u>EP - A - 0 147 561</u> (SIEMENS AG) * Totality; especially page 4, lines 8-17; page 6, lines 25-27; page 6, last line - page 7, line 3 *	1, 2, 4, 5, 6, 8, 12, 14, 15	TECHNICAL FIELDS SEARCHED (Int. CL5) G 01 T 1/00 H 01 L 31/00
A	<u>US - A - 4 658 141</u> (WILT) * Totality *	1, 9, 10, 12	
A	<u>US - A - 4 631 409</u> (SPARACIA) * Totality *	1, 9, 10, 12	
A	PATENT ABSTRACTS OF JAPAN, unexamined applications, P field, vol. 8, no. 147, July 10, 1984 THE PATENT OFFICE JAPANESE	1-3	
The present search report has been drawn up for all claims			
Place of search	Date of completion of the search	Examiner	
VIENNA	30-11-1992	WERNER	
CATEGORY OF CITED DOCUMENTS		T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document	
X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document			



European Patent
Office

EUROPEAN SEARCH REPORT

Application Number

-2-

EP 92307519.6

DOCUMENTS CONSIDERED TO BE RELEVANT			CLASSIFICATION OF THE APPLICATION (Int. CL.5)
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	
	<p>GOVERNMENT page 22 P 285 * NO. 59-44 678 (HITACHI) *</p> <p>-----</p>		
			TECHNICAL FIELDS SEARCHED (Int. CL.5)
<p>The present search report has been drawn up for all claims</p>			
Place of search VIENNA	Date of completion of the search 30-11-1992	Examiner WERNER	
CATEGORY OF CITED DOCUMENTS <p>X : particularly relevant if taken alone Y : particularly relevant if combined with another document of the same category A : technological background O : non-written disclosure P : intermediate document</p> <p>T : theory or principle underlying the invention E : earlier patent document, but published on, or after the filing date D : document cited in the application L : document cited for other reasons & : member of the same patent family, corresponding document</p>			